



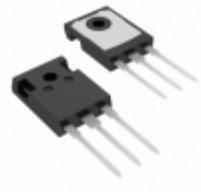
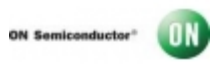



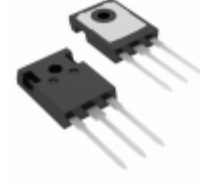
	FGH80N60FD2TU	
	Hersteller-Teilenummer:	FGH80N60FD2TU
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	IGBT 600V 80A 290W TO247
	Datenblätter:	 FGH80N60FD2TU.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 32663 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FGH80N60FD2TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	IGBT 600V 80A 290W TO247
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs
Teilstatus	32663 pcs Stock
detaillierte Beschreibung	IGBT Field Stop 600V 80A 290W Through Hole TO-247
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	290W
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Rückwärts-Erholzeit (Trr)	61ns
Strom - Kollektor (Ic) (max)	80A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	Field Stop
VCE (on) (Max) @ Vge, Ic	2.4V @ 15V, 40A
Strom - Collector Pulsed (Icm)	160A
Schaltenergie	1mJ (on), 520µJ (off)
Gate-Ladung	120nC
Td (ein / aus) bei 25 ° C	21ns/126ns
Testbedingung	400V, 40A, 10 Ohm, 15V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)




FGH80N60FD2TU ist neu im Original, Suche FGH80N60FD2TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FGH80N60FD2TU AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FGH80N60FD2TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FGH80N60FD2 FSC FGH80N60FD2 FSC</p>	 <p>FGH80N60FD2TU(FGH80N60FD2) FAIRCHILD FGH80N60FD2TU(FGH80N60FD2) FAIRCHILD</p>	 <p>FGH80N60FD2TU Fairchild/ON Semiconductor IGBT 600V 80A 290W TO247</p>	 <p>FGH75T65UPD-F155 AMI Semiconductor / ON Semiconductor 650V,75A FIELD STOP TRENCH IGBT</p>
 <p>FGH80N60RUF Fairchild/ON Semiconductor FGH80N60RUF FAIRCHILD</p>	 <p>FGH80N60FDTU Fairchild/ON Semiconductor IGBT 600V 80A 290W TO247</p>	 <p>FGH80N60FD Original FGH80N60FD Original</p>	 <p>FGH80N60FDTU AMI Semiconductor / ON Semiconductor IGBT 600V 80A 290W TO247</p>

heiße Teile

Mehr

 FGH40N60SMD	 FGH40N60SMD	 FGH40N60UF	 D FGH40N60UFD	 FGH40N60UFDTU
 FGH40N60UFDTU	 FGH40N60UFTU	 D FGH40N60UFTU	 FGH40N65UFD	 FGH40N65UFDTU
 FGH40N65UFDTU	 FGH40N6S2	 FGH40N6S2	 FGH40N6S2D	 FGH40N6S2D
 D FGH40T100SMD	 FGH40T100SMD	 FGH40T120SMD	 FGH40T120SMD	 FGH40T65SHDF
 FGH40T65SPD	 FGH50N6S2	 FGH50N6S2	 FGH50N6S2D	 FGH50N6S2D
 FGH50T65SQD	 FGH50T65UPD	 D FGH50T65UPD	 FGH60N60SF	 FGH60N60SFD
 FGH60N60SMD	 D FGH60N60SMD	 FGH60N60UFD	 FGH60N6S2	 FGH60N6S2
 FGH60T65SHD	 FGH75N60SF	 FGH75N60SFTU	 FGH75N60SFTU	 FGH75N60UF
 FGH75N60UFTU	 FGH75N60UFTU	 FGH75T65UPD	 D FGH75T65UPD	 FGH80N60FD
 FGH80N60FD2	 FGH80N60FD2TU	 FGH80N60FDTU	 FGH80N60FDTU	 FGH80N60RUF

Contact us:Info@Y-IC.com

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